

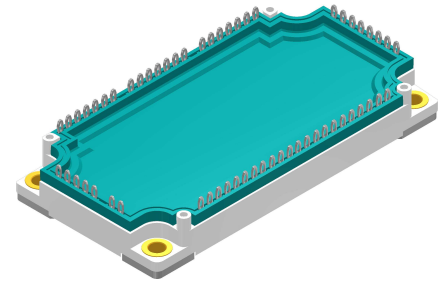
Standard Rectifier Module

3~ Rectifier
$V_{RRM} = 1600\text{ V}$
$I_{DAV} = 660\text{ A}$
$I_{FSM} = 5000\text{ A}$

3~ Rectifier Bridge + NTC

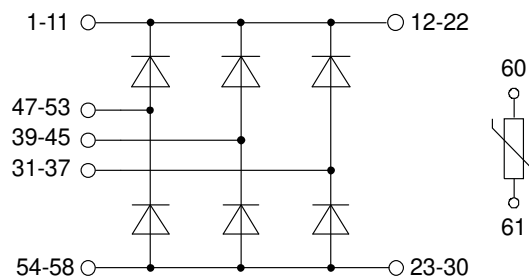
Part number

MDMA660U1600PTEH



Backside: isolated

 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: E3-Pack

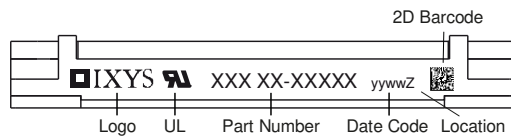
- Isolation Voltage: 4300 V~
- Industry standard outline
- RoHS compliant
- PressFit-Pins for PCB mounting
- Height: 17 mm
- Base plate: Copper internally DCB isolated
- Advanced power cycling
- Phase Change Material available

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Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage			$T_{VJ} = 25^{\circ}C$		1700	V
V_{RRM}	max. repetitive reverse blocking voltage			$T_{VJ} = 25^{\circ}C$		1600	V
I_R	reverse current	$V_R = 1600$ V		$T_{VJ} = 25^{\circ}C$		200	μA
		$V_R = 1600$ V		$T_{VJ} = 150^{\circ}C$		3	mA
V_F	forward voltage drop	$I_F = 220$ A		$T_{VJ} = 25^{\circ}C$		1.28	V
		$I_F = 660$ A				1.95	V
		$I_F = 220$ A		$T_{VJ} = 125^{\circ}C$		1.19	V
		$I_F = 660$ A				1.95	V
I_{DAV}	bridge output current	$T_C = 85^{\circ}C$	rectangular	$T_{VJ} = 150^{\circ}C$		660	A
			$d = \frac{1}{3}$				
V_{FO}	threshold voltage	} for power loss calculation only		$T_{VJ} = 150^{\circ}C$		0.77	V
r_F	slope resistance					1.8	m Ω
R_{thJC}	thermal resistance junction to case					0.15	K/W
R_{thCH}	thermal resistance case to heatsink				0.075		K/W
P_{tot}	total power dissipation			$T_C = 25^{\circ}C$		830	W
I_{FSM}	max. forward surge current	$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 45^{\circ}C$		5.00	kA
		$t = 8,3$ ms; (60 Hz), sine		$V_R = 0$ V		5.40	kA
		$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 150^{\circ}C$		4.25	kA
		$t = 8,3$ ms; (60 Hz), sine		$V_R = 0$ V		4.59	kA
I^2t	value for fusing	$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 45^{\circ}C$		125.0	kA ² s
		$t = 8,3$ ms; (60 Hz), sine		$V_R = 0$ V		121.3	kA ² s
		$t = 10$ ms; (50 Hz), sine		$T_{VJ} = 150^{\circ}C$		90.3	kA ² s
		$t = 8,3$ ms; (60 Hz), sine		$V_R = 0$ V		87.6	kA ² s
C_J	junction capacitance	$V_R = 400$ V; $f = 1$ MHz		$T_{VJ} = 25^{\circ}C$		208	pF

Package E3-Pack			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			30	A
T_{VJ}	virtual junction temperature		-40		175	°C
T_{op}	operation temperature		-40		150	°C
T_{stg}	storage temperature		-40		125	°C
Weight				270		g
M_D	mounting torque		3		6	Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	6.0			mm
$d_{Spb/Apb}$		terminal to backside	12.0			mm
V_{ISOL}	isolation voltage	t = 1 second	4300			V
		t = 1 minute	3600			V


Part description

M = Module
 D = Diode
 M = Standard Rectifier
 A = (up to 1800V)
 660 = Current Rating [A]
 U = 3- Rectifier Bridge
 1600 = Reverse Voltage [V]
 PT = PressFit-Pin, Thermistor
 EH = E3-Pack
 - = Hyphen
 PC = Phase Change Material

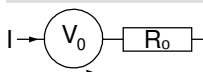
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDMA660U1600PTEH	MDMA660U1600PTEH	Blister	24	515654
Alternative	MDMA660U1600PTEH-PC	MDMA660U1600PTEH	Blister	24	514475

Temperature Sensor NTC

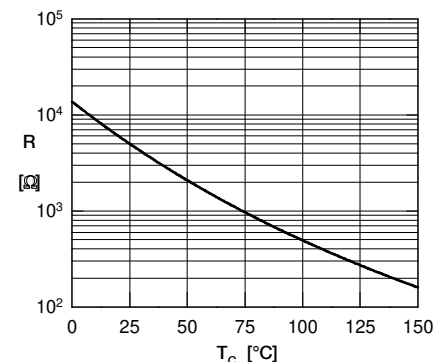
Symbol	Definition	Conditions	min.	typ.	max.	Unit
R_{25}	resistance	$T_{VJ} = 25^\circ$	4.85	5	5.15	k Ω
$B_{25/50}$	temperature coefficient			3375		K

Equivalent Circuits for Simulation

* on die level

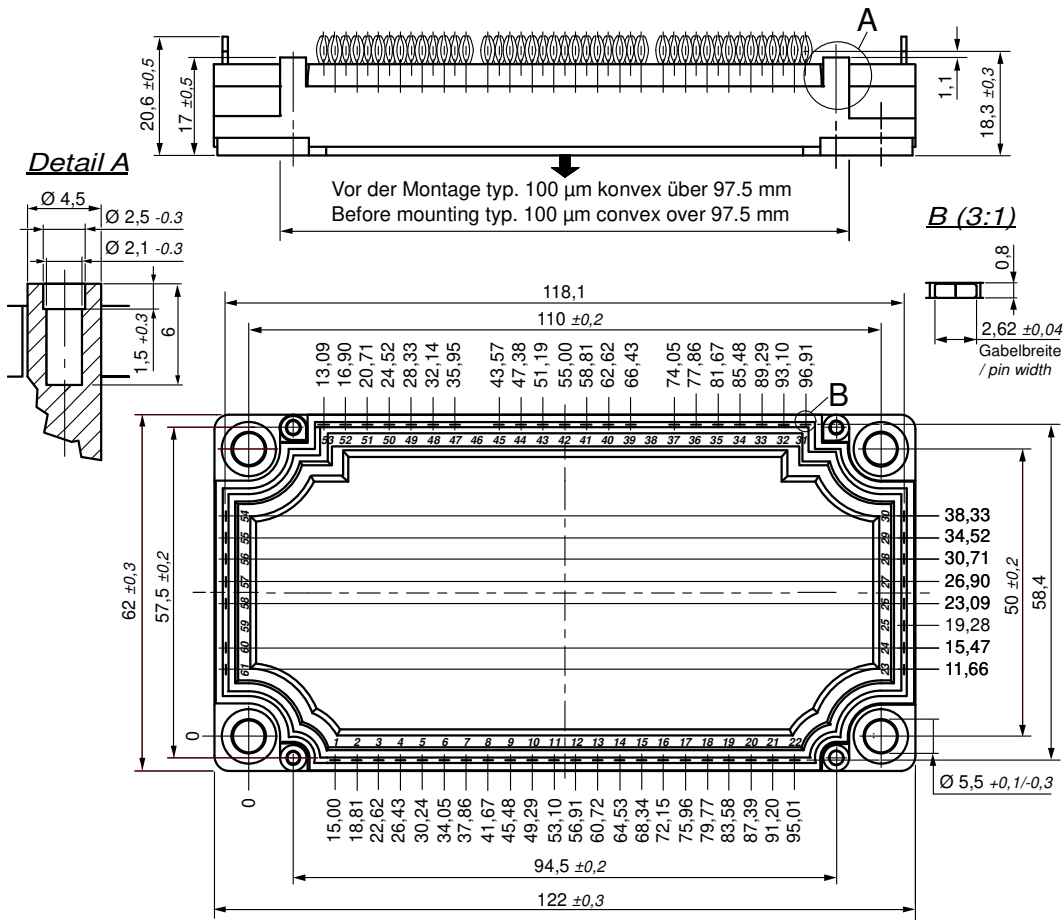
 $T_{VJ} = 150^\circ\text{C}$

Rectifier

$V_{0 \max}$	threshold voltage	0.77				V
$R_{0 \max}$	slope resistance *	0.57				m Ω





Outlines E3-Pack



Bemerkung / Note:

- Nichttolerierete Maße nach / Measure without tolerances according DIN ISO 2768-T1-m
- PCB-Lochmuster / PCB hole pattern: **see pin position**
- Toleranz Pin-Position und PCB-Lochmuster / Tolerance of pin position and PCB hole pattern: $\oplus 0.1$
- Bohrlochdurchmesser / Diameter of drill: **Ø 2.35 mm**
- Endlochdurchmesser / Diameter of plated holes: **Ø 2.14 - 2.29 mm** (Cu thickness in via typ. 50 μm)
- Beschichtung / Plating: **chem. Sn max. 15 μm**
- Einpresskraft / Insert Force: per terminal with a typ. insert speed of 7 mm/s: **typ. 90 N**
- Weitere Angaben / Further information: www.ixys.com **Application note IXAN0077**
- Montageanleitung / Mounting instruction: www.ixys.com **Application note IXAN0024**

Detail A: PCB-Montage / Mounting on PCB¹

- Empfohlene, selbstschneidende Schraube / Recommended, self-tapping screw: **EJOT PT®** (Größe / size: **K25**)¹
- Max. Schraubenlänge / Max. screw length: **PCB-Dicke / thickness + 6 mm** (max. Lochtiefe / hole depth)¹
- Empfohlenes Drehmoment / Recommended mounting torque: **1.5 Nm**

